

UNISONIC TECHNOLOGIES CO., LTD

UT3419

20V, 3.5A P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

DESCRIPTION

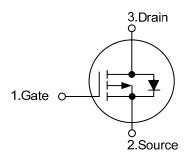
The UTC **UT3419** is a P-channel enhancement MOSFET providing designers with excellent $R_{DS(ON)}$, low gate charge. The gate voltage is as low as 2.5V.

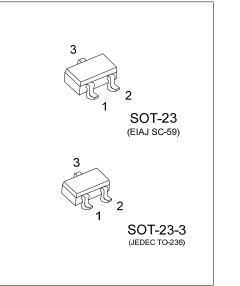
The UTC **UT3419** can be applied in PWM applications or used as a load switch.

FEATURES

- * $R_{DS(ON)} \le 70 \text{ m}\Omega @ V_{GS}$ =-10V, I_D =-3.5A
- * $R_{DS(ON)} \le 80 \text{ m}\Omega @ V_{GS}=-4.5V, I_D=-3.0A$
- * $R_{DS(ON)}$ ≤ 130 mΩ @ V_{GS} =-2.5V, I_D =-1.0A

SYMBOL





Power MOSFET

ORDERING INFORMATION

Ordering Number		Deekees	Pin Assignment			Decking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UT3419L-AE2-R	UT3419G-AE2-R	SOT-23-3	G	S	D	Tape Reel	
UT3419L-AE3-R	UT3419G-AE3-R	SOT-23	G	S	D	Tape Reel	
Note: Pin Assignment: G: Gat	te S: Source D: Drain						

UT3419 <u>G-AE2-</u> R		
	(1)Packing Type	(1) R: Tape Reel
	(2)Package Type	(2) AE2: SOT-23-3, AE3: SOT-23
	(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain to Source Voltage		V _{DSS}	-20	V
Gate to Source Voltage		V _{GSS}	±12	V
Continuous Drain Current (Note 1)	T _A =25°C	I _D	-3.5	А
	T _A =70°C		-2.8	А
Pulsed Drain Current (Note 2)		I _{DM}	-15	А
Total Dower Dissinction (Nate 4)	T _A =25°C		0.6	W
Total Power Dissipation (Note 1)	T _A =70°C	P _D	0.4	W
Junction Temperature		TJ	-55 ~ +150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
hundright Angleight (Nate 4)	t ≤ 10s	0	208	°C/W
Junction to Ambient (Note 1)	Steady-State	θ _{JA}	290	°C/W

Notes: 1. The value of θ_{JA} is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with T_A =25°C. The value in any a given application depends on the user's specific board design. The current rating is based on the $t \le 10s$ thermal resistance rating.

2. Repetitive rating, pulse width limited by junction temperature.



				1		
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, Ι _D =-250μΑ	-20			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =-16V,V _{GS} =0V			-0.5	μA
Cata Course Laskage Current	I _{GSS}	$V_{DS}=0V$, $V_{GS}=\pm10V$			±100	nA
Gate-Source Leakage Current		V _{DS} =0V ,V _{GS} =±12V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} = V _{GS} , Ι _D =-250μΑ	-0.7		-1.4	V
		V _{GS} =-10V,I _D =-3.5A			70	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-3.0A			80	mΩ
		V _{GS} =-2.5V, I _D =-1.0A			130	mΩ
DYNAMIC PARAMETERS				÷		
Input Capacitance	CISS			585		pF
Output Capacitance	Coss	V _{DS} =-10V, V _{GS} =0V, f=1MHz		130		pF
Reverse Transfer Capacitance	C _{RSS}			110		pF
Gate Resistance	R_{G}	V _{GS} =0V, V _{DS} =0V, f=1MHz			13	Ω
SWITCHING PARAMETERS				÷		
Total Gate Charge	Q_{G}			8.5		nC
Gate-Source Charge	Q_{GS}	V _{DS} =-10V, V _{GS} =-4.5V, I _D =-3.5A		2		nC
Gate-Drain Charge	Q_{GD}			2		nC
Turn-ON Delay Time	t _{D(ON)}			4		ns
Turn-ON Rise Time	t _R	V _{DS} =-10V, V _{GS} =-10V, I _D =-3.5A,		17		ns
Turn-OFF Delay Time	t _{D(OFF)}	R _G =3.0Ω		28		ns
Turn-OFF Fall Time	t⊧			20		ns
SOURCE- DRAIN DIODE RATINGS A	ND CHARAC	CTERISTICS		-		
Maximum Body-Diode Continuous Current	Is				-2	А
Drain-Source Diode Forward Voltage	V _{SD}	I _S =-1.0A, V _{GS} =0V			-0.95	V

■ ELECTRICAL CHARACTERISTICS (TJ=25°C, unless otherwise specified)

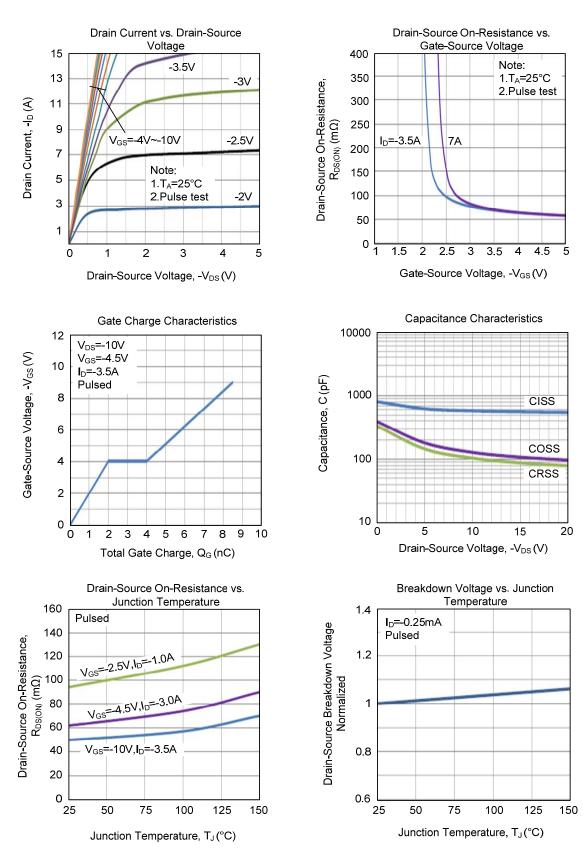
Notes: 1. The θ_{JA} is the sum of the thermal impedance from junction to lead θ_{JL} and lead to ambient.

2. These tests are performed with the device mounted on 1 in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^{\circ}C$. The SOA curve provides a single pulse rating.



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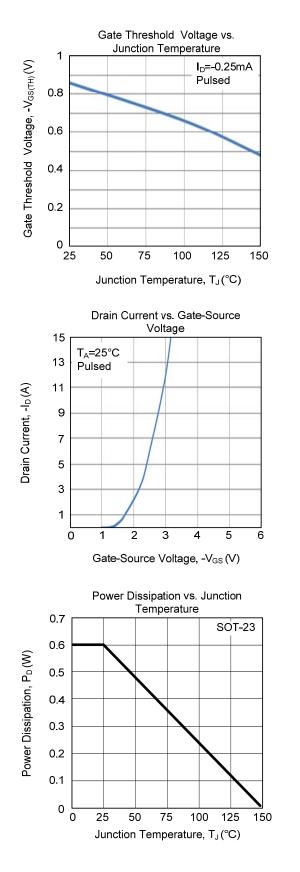
TYPICAL CHARACTERISTICS

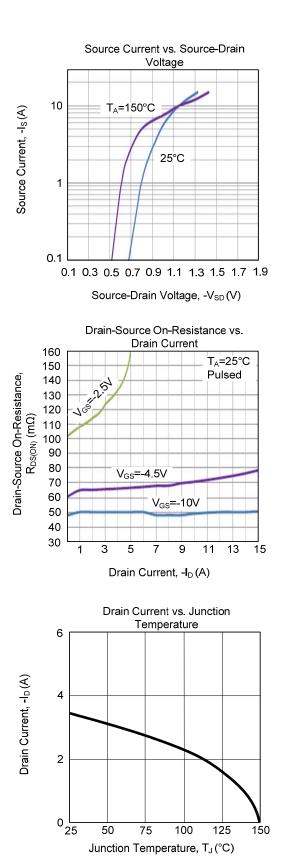






■ TYPICAL CHARACTERISTICS (Cont.)

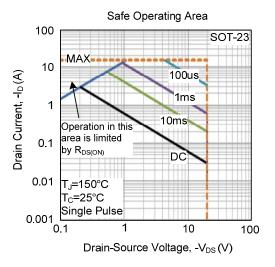




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■ TYPICAL CHARACTERISTICS (Cont.)



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